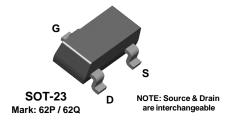


# **J201 J202**

# **MMBFJ201** MMBFJ202





# **N-Channel General Purpose Amplifier**

This device is designed primarily for low level audio and general purpose applications with high impedance signal sources. Sourced from Process 52.

## **Absolute Maximum Ratings\***

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{DG}$	Drain-Gate Voltage	40	V
V <sub>GS</sub>	Gate-Source Voltage	- 40	V
I <sub>GF</sub>	Forward Gate Current	50	mA
T <sub>J</sub> ,T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### **Thermal Characteristics** TA = 25°C unless otherwise noted

Symbol	Characteristic	М	Max		
		J202-203	*MMBFJ202-203		
$P_D$	Total Device Dissipation	625	350	mW	
	Derate above 25°C	5.0	2.8	mW/°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125		°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	556	°C/W	

<sup>\*</sup>Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

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<sup>1)</sup> These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

(continued)

## **Electrical Characteristics**

TA = 25°C unless otherwise noted

Symbol	Parameter	meter Test Conditions				Units
OFF CHAI	RACTERISTICS					
$V_{(BR)GSS}$	Gate-Source Breakdown Voltage	$I_G = -1.0 \mu A, V_{DS} = 0$		- 40		V
I <sub>GSS</sub>	Gate Reverse Current	V <sub>GS</sub> = - 20 V, V <sub>DS</sub> = 0			-100	pА
V <sub>GS(off)</sub>	Gate-Source Cutoff Voltage	V <sub>DS</sub> = 20 V, I <sub>D</sub> = 10 nA	201 202	- 0.3 - 0.8	- 1.5 - 4.0	V V

## **ON CHARACTERISTICS**

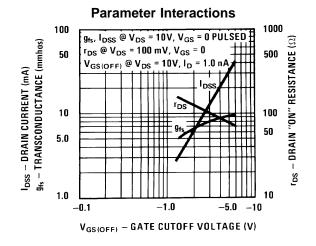
I <sub>DSS</sub>	Zero-Gate Voltage Drain Current*	$V_{DS} = 20 \text{ V}, I_{GS} = 0$	201	0.2	1.0	mA
	-		202	0.9	4.5	mA

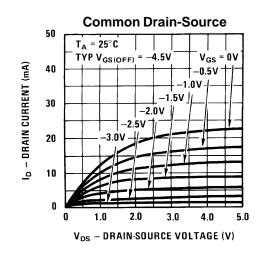
## SMALL SIGNAL CHARACTERISTICS

Yfs	Forward Transfer Admittance	$V_{DS} = 20 \text{ V}, f = 1.0 \text{ kHz}$	201	500	μmhos
•			202	1000	μmhos

<sup>\*</sup>Pulse Test: Pulse Width ≤ 300 μS

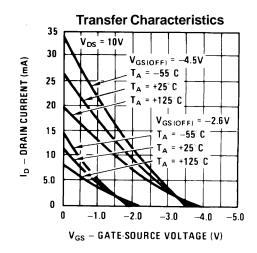
## **Typical Characteristics**

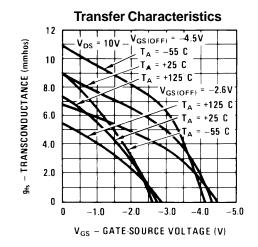


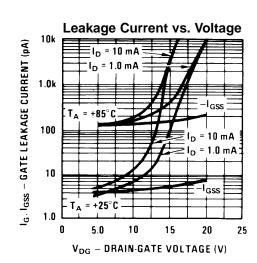


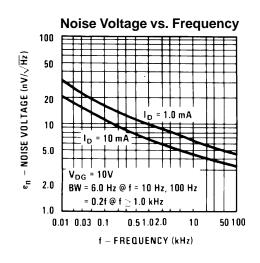
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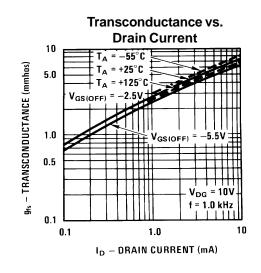


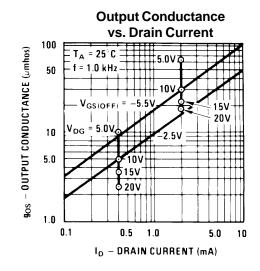






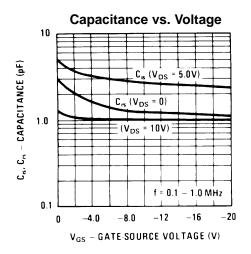




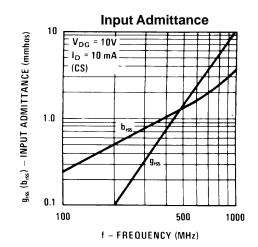


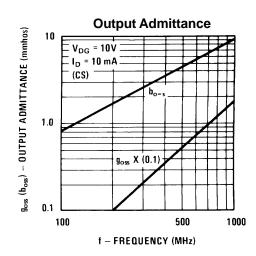
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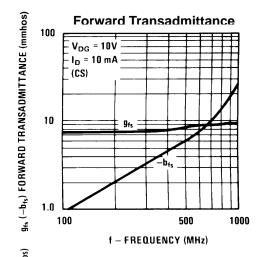
## Typical Characteristics (continued)

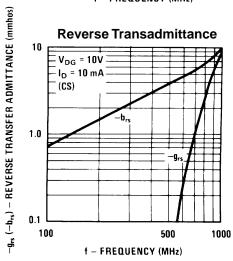


## **Common Source Characteristics**



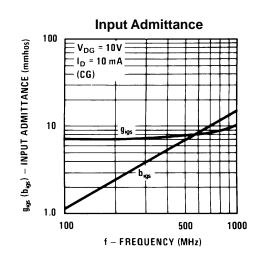


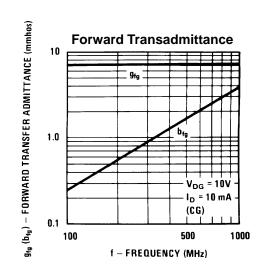


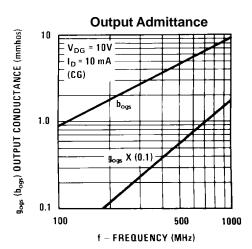


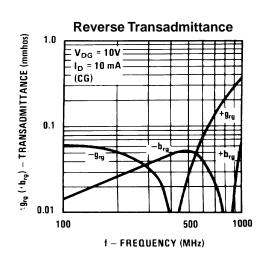
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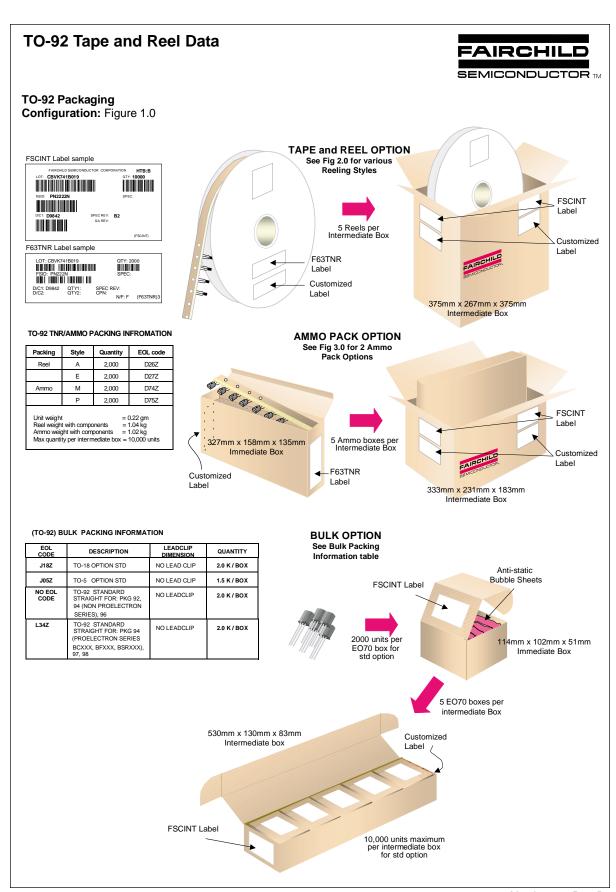
## **Common Gate Characteristics**









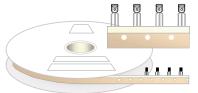


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## TO-92 Tape and Reel Data, continued

# **TO-92 Reeling Style Configuration:** Figure 2.0

## Machine Option "A" (H)



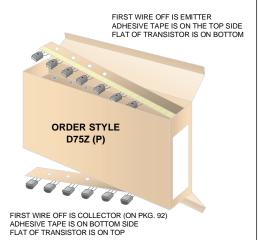
Style "A", D26Z, D70Z (s/h)

# Machine Option "E" (J)

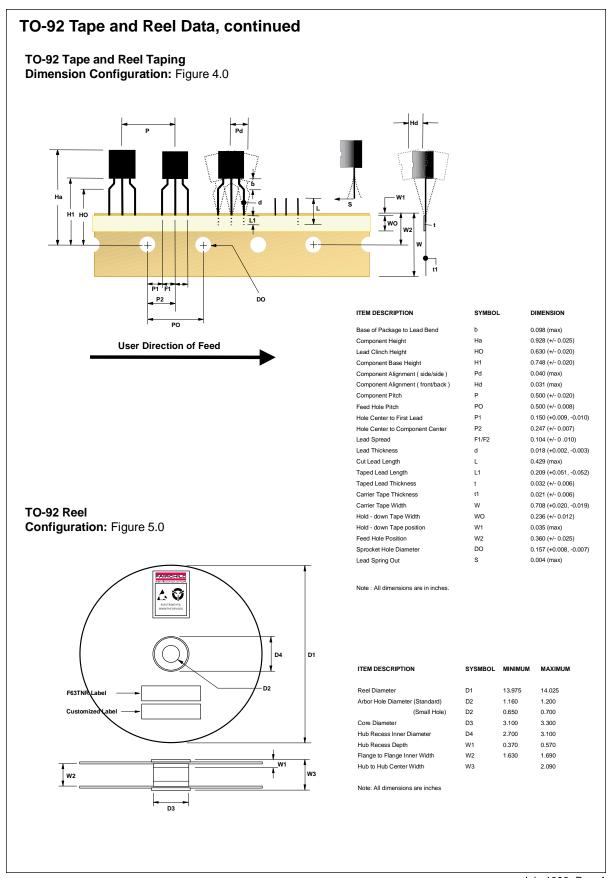
Style "E", D27Z, D71Z (s/h)

# **TO-92 Radial Ammo Packaging Configuration:** Figure 3.0





September 1999, Rev. B

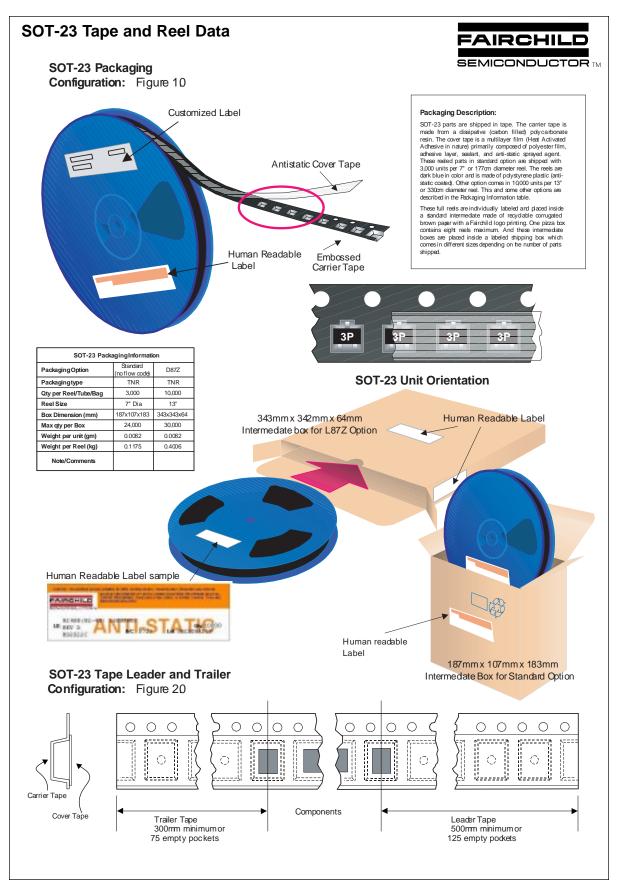


# **TO-92 Package Dimensions** FAIRCHILD SEMICONDUCTOR TM TO-92 (FS PKG Code 92, 94, 96) Scale 1:1 on letter size paper Dimensions shown below are in: inches [millimeters] Part Weight per unit (gram): 0.1977 0.185 4.70 0.170 4.32 TO-92 (92,94,96) 94 96 B F В В В D D 2 В S С G Ε Ø0.060 [Ø1.52] G В S С G 0.010 [0.254] DEEP 5.0°TYP.

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0.095 0.084 2.13

January 2000, Rev. B

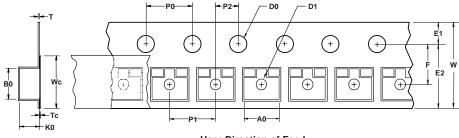


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# SOT-23 Tape and Reel Data, continued

## **SOT-23 Embossed Carrier Tape**

Configuration: Figure 3.0



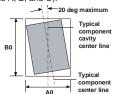
User Direction of Feed	

					Di	mension	s are in n	nillimete	r					
Pkg type	Α0	В0	w	D0	D1	E1	E2	F	P1	P0	K0	Т	Wc	Тс
<b>SOT-23</b> (8mm)	3.15 +/-0.10	2.77 +/-0.10	8.0 +/-0.3	1.55 +/-0.05	1.125 +/-0.125	1.75 +/-0.10	6.25 min	3.50 +/-0.05	4.0 +/-0.1	4.0 +/-0.1	1.30 +/-0.10	0.228 +/-0.013	5.2 +/-0.3	0.06 +/-0.02

Notes: A0, B0, and K0 dimensions are determined with respect to the EIA/Jedec RS-481 rotational and lateral movement requirements (see sketches A, B, and C).



Sketch A (Side or Front Sectional View)
Component Rotation



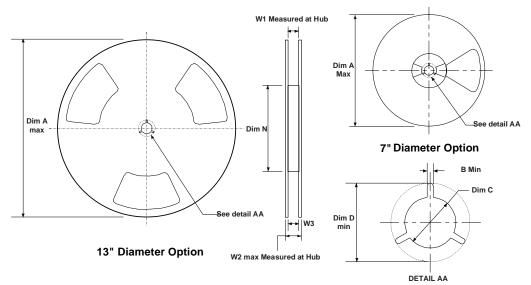
Sketch B (Top View)
Component Rotation



Sketch C (Top View)

Component lateral movement

## SOT-23 Reel Configuration: Figure 4.0

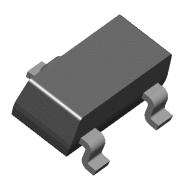


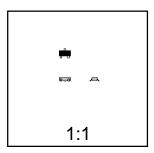
	Dimensions are in inches and millimeters								
Tape Size	Reel Option	Dim A	Dim B	Dim C	Dim D	Dim N	Dim W1	Dim W2	Dim W3 (LSL-USL)
8mm	7" Dia	7.00 177.8	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	2.165 55	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4	0.311 - 0.429 7.9 - 10.9
8mm	13" Dia	13.00 330	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	4.00 100	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4	0.311 - 0.429 7.9 - 10.9

## **SOT-23 Package Dimensions**



# SOT-23 (FS PKG Code 49)

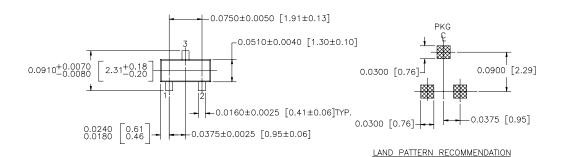


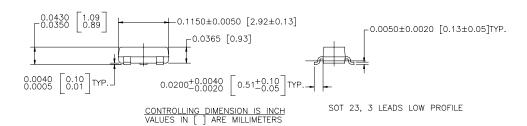


Scale 1:1 on letter size paper

Dimensions shown below are in: inches [millimeters]

Part Weight per unit (gram): 0.0082





NOTE: UNLESS OTHERWISE SPECIFIED

- 1. STANDARD LEAD FINISH 150 MICROINCHES / 3.81 MICROMETERS MINIMUM TIN / LEAD (SOLDER) ON ALLOY 42
- 2. REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE G, DATED JUL 1993

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September 1998, Rev. A1

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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